4-bit dual supply buffer/line driver; 3-state Rev. 2 — 3 August 2023

1. General description

The 74LVC4T3144-Q100 is a 4-bit, dual-supply level translating buffer with 3-state outputs. It features four data inputs (An and B4), four data outputs (YBn and YA4), and an output enable input (\overline{OE}). The device is configured to translate three inputs from V_{CC(A)} to V_{CC(B)} and one input from V_{CC(B)} to V_{CC(A)}. \overline{OE} , An and YA4 are referenced to V_{CC(A)} and YBn and B4 are referenced to V_{CC(B)}. A HIGH on \overline{OE} causes the outputs to assume a high-impedance OFF-state.

The device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables outputs, preventing any damaging backflow current through the device when it is powered down. In suspend mode when either $V_{CC(A)}$ or $V_{CC(B)}$ are at GND level, all outputs are in the high-impedance OFF-state.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

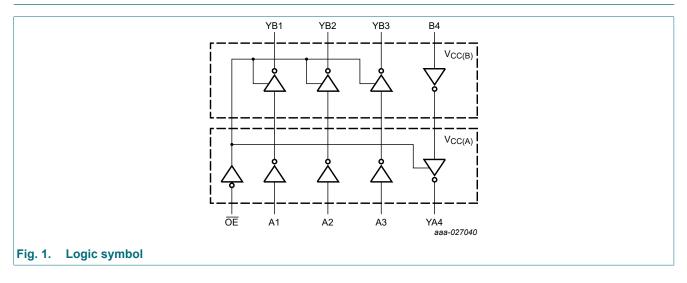
- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range:
 - V_{CC(A)}: 1.2 V to 5.5 V
 - V_{CC(B)}: 1.2 V to 5.5 V
- High noise immunity
- Maximum data rates:
 - 200 Mbps (3.3 V to 5.0 V translation)
 - 140 Mbps (translate to 3.3 V))
 - 100 Mbps (translate to 2.5 V)
 - 75 Mbps (translate to 1.8 V)
 - 60 Mbps (translate to 1.5 V)
- Suspend mode
- Latch-up performance exceeds 100 mA per JESD 78B Class II
- ±24 mA output drive (V_{CC} = 3.0 V)
- Inputs accept voltages up to 5.5 V
- Low power consumption: 30 µA maximum I_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- Complies with JEDEC standards:
 - JESD8-11A (1.4 V to 1.6 V)
 - JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8C (3.0 V to 3.6 V)
 - JESD12-6 (4.5 V to 5.5 V)
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V

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3. Ordering information

Table 1. Ordering information								
Type number	Package							
	Temperature range	Name	Description	Version				
74LVC4T3144PW-Q100	-40 °C to +125 °C	TSSOP14	plastic thin shrink small outline package; 14 leads; body width 4.4 mm	<u>SOT402-1</u>				

4. Functional diagram



5. Pinning information

5.1. Pinning

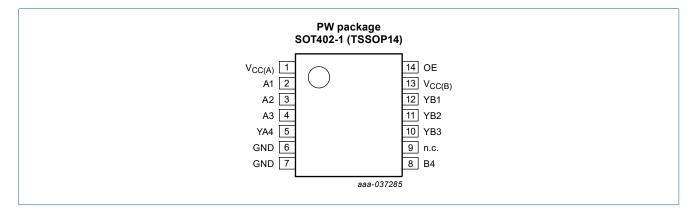


Table 2. Pin des	cription	
Symbol	Pin	Description
V _{CC(A)}	1	supply voltage A (An inputs, YA4 output and \overline{OE} input are referenced to V _{CC(A)})
A1, A2, A3	2, 3, 4	data input
YA4	5	data output
GND	6, 7	ground (0 V)
B4	8	data input
n.c.	9	not connected
YB3, YB2, YB1	10, 11, 12	data output
V _{CC(B)}	13	supply voltage B (YBn outputs and B4 input are referenced to $V_{CC(B)}$)
OE	14	output enable input (active LOW)

5.2. Pin description

6. Functional description

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Table 3. Function table [1] Supply voltage	Control	Input	Output	
V _{CC(A)} , V _{CC(B)}	OE [2]	An, B4[2]	YBn, YA4[2]	
1.2 V to 5.5 V	L	L	L	
1.2 V to 5.5 V	L	Н	Н	
1.2 V to 5.5 V	Н	Х	Z	
GND[3]	X	Х	Z	

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

[2] The An inputs, YA4 output and \overline{OE} input are referenced to $V_{CC(A)}$; The YBn outputs and B4 input are referenced to $V_{CC(B)}$. [3] If at least one of $V_{CC(A)}$ or $V_{CC(B)}$ is at GND level, the device goes into suspend mode.

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7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC(A)}	supply voltage A			-0.5	+6.5	V
V _{CC(B)}	supply voltage B			-0.5	+6.5	V
I _{IK}	input clamping current	V _I < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+6.5	V
I _{OK}	output clamping current	V _O < 0 V		-50	-	mA
Vo	output voltage	Active mode	[1] [2] [3]	-0.5	V _{CCO} + 0.5	V
		Suspend or 3-state mode	[1]	-0.5	+6.5	V
I _O	output current	$V_{O} = 0 V$ to V_{CCO}	[2]	-	±50	mA
I _{CC}	supply current	$I_{CC(A)}$ or $I_{CC(B)}$; per V_{CC} pin		-	100	mA
I _{GND}	ground current	per GND pin		-100	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C	[4]	-	500	mW

[1] The minimum input voltage ratings and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] V_{CCO} is the supply voltage associated with the output port.

[3] V_{CCO} + 0.5 V should not exceed 6.5 V.

[4] For SOT402-1 (TSSOP14) package: Ptot derates linearly with 7.3 mW/K above 81 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC(A)}	supply voltage A		1.2	5.5	V
V _{CC(B)}	supply voltage B		1.2	5.5	V
VI	input voltage		0	5.5	V
Vo	output voltage	Active mode [1]	0	V _{CCO}	V
		Suspend or 3-state mode	0	5.5	V
T _{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CCI} = 1.2 V [2]	-	20	ns/V
		V _{CCI} = 1.4 V to 1.95 V	-	20	ns/V
		V _{CCI} = 2.3 V to 2.7 V	-	20	ns/V
		V _{CCI} = 3 V to 3.6 V	-	10	ns/V
		V _{CCI} = 4.5 V to 5.5 V	-	5	ns/V

[1] V_{CCO} is the supply voltage associated with the output port.

[2] V_{CCI} is the supply voltage associated with the input port.

9. Static characteristics

Table 6. Typical static characteristics at T_{amb} = 25 °C

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{OH}	HIGH-level output voltage	YBn, YA4; V _I = V _{IH} or V _{IL}	[1]				
		I _O = -3 mA; V _{CCO} = 1.2 V		-	1.09	-	V
V _{OL}	LOW-level output voltage	YBn, YA4; V _I = V _{IH} or V _{IL}					
		I _O = 3 mA; V _{CCO} = 1.2 V	[1]	-	0.07	-	V
l _l	input leakage current	An, B4 and \overline{OE} input; V _I = 0 V to 5.5 V; V _{CCI} = 1.2 V to 5.5 V	[2]	-	-	±1	μA
I _{OZ}	OFF-state output current	YBn, YA4; $V_0 = 0$ V or V_{CCO} ; $V_{CCO} = 1.2$ V to 5.5 V	[1]	-	-	±1	μA
		YBn, YA4; suspend mode; V _O = 0 V or V _{CCO} ; V _{CC(A)} = 5.5 V; V _{CC(B)} = 0 V	[1]	-	-	±1	μA
		YBn, YA4; suspend mode; $V_0 = 0 V \text{ or } V_{CCO}$; $V_{CC(A)} = 0 V$; $V_{CC(B)} = 5.5 V$	[1]	-	-	±1	μA
I _{OFF}	power-off leakage current	A port; V ₁ or V ₀ = 0 V to 5.5 V; V _{CC(A)} = 0 V; V _{CC(B)} = 1.2 V to 5.5 V		-	-	±1	μA
		B port; V ₁ or V ₀ = 0 V to 5.5 V; V _{CC(B)} = 0 V; V _{CC(A)} = 1.2 V to 5.5 V		-	-	±1	μA
CI	input capacitance	An, B4 and \overline{OE} input; V _I = 0 V or 3.3 V; V _{CC(A)} = 3.3 V; V _{CC(B)} = 3.3 V		-	3	-	pF
C _O	output capacitance	$\label{eq:VBn} \begin{array}{l} \mbox{YBn, YA4 output; V}_{O} = 0 \mbox{ V or } 3.3 \mbox{ V;} \\ \hline \mbox{OE input} = 3.3 \mbox{ V; V}_{CC(A)} = 3.3 \mbox{ V;} \\ \mbox{V}_{CC(B)} = 3.3 \mbox{ V} \end{array}$		-	6.5	-	pF

[1] V_{CCO} is the supply voltage associated with the output port.

[2] V_{CCI} is the supply voltage associated with the input port.

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40 °C to	• +85 °C	-40 °C to	+125 °C	Unit
			Min	Max	Min	Max	
V _{IH}	HIGH-level	data input [1]					
	input voltage	V _{CCI} = 1.2 V	0.8V _{CCI}	-	0.8V _{CCI}	-	V
		V _{CCI} = 1.4 V to 1.95 V	0.65V _{CCI}	-	0.65V _{CCI}	-	V
		V _{CCI} = 2.3 V to 2.7 V	1.7	-	1.7	-	V
		V _{CCI} = 3.0 V to 3.6 V	2.0	-	2.0	-	V
		V _{CCI} = 4.5 V to 5.5 V	0.7V _{CCI}	-	0.7V _{CCI}	-	V
		OE input					
		V _{CCI} = 1.2 V	0.8V _{CC(A)}	-	0.8V _{CC(A)}	-	V
		V _{CCI} = 1.4 V to 1.95 V	0.65V _{CC(A)}	-	0.65V _{CC(A)}	-	V
		V _{CCI} = 2.3 V to 2.7 V	1.7	-	1.7	-	V
		V _{CCI} = 3.0 V to 3.6 V	2.0	-	2.0	-	V
		V _{CCI} = 4.5 V to 5.5 V	0.7V _{CC(A)}	-	0.7V _{CC(A)}	-	V

4-bit dual supply buffer/line driver; 3-state

Symbol	Parameter	Conditions		-40 °C t	o +85 °C	-40 °C to	o +125 °C	Unit
				Min	Max	Min	Мах	
VIL	LOW-level	data input	[1]					
	input voltage	V _{CCI} = 1.2 V		-	0.2V _{CCI}	-	0.2V _{CCI}	V
		V _{CCI} = 1.4 V to 1.95 V		-	0.35V _{CCI}	-	0.35V _{CCI}	V
		V _{CCI} = 2.3 V to 2.7 V		_	0.7	-	0.7	V
		V _{CCI} = 3.0 V to 3.6 V		_	0.8	-	0.8	V
		V _{CCI} = 4.5 V to 5.5 V		-	0.3V _{CCI}	-	0.3V _{CCI}	V
		OE input						
		V _{CCI} = 1.2 V		-	0.2V _{CC(A)}	-	0.2V _{CC(A)}	V
		V _{CCI} = 1.4 V to 1.95 V		_	0.35V _{CC(A)}	-	0.35V _{CC(A)}	V
		V _{CCI} = 2.3 V to 2.7 V		_	0.7	-	0.7	V
		V _{CCI} = 3.0 V to 3.6 V		_	0.8	-	0.8	V
		V _{CCI} = 4.5 V to 5.5 V		-	0.3V _{CC(A)}	-	0.3V _{CC(A)}	V
V _{он}	HIGH-level	$V_{I} = V_{IH}$			00(1)			
	output voltage	$I_{O} = -100 \ \mu\text{A};$ $V_{CCO} = 1.2 \ V \text{ to } 4.5 \ V$	[2]	V _{CCO} - 0.1	-	V _{CCO} - 0.1	-	V
		I _O = -6 mA; V _{CCO} = 1.4 V		1.0	-	1.0	-	V
		I _O = -8 mA; V _{CCO} = 1.65 V		1.2	-	1.2	-	V
		I _O = -12 mA; V _{CCO} = 2.3 V		1.9	-	1.9	-	V
		I _O = -24 mA; V _{CCO} = 3.0 V		2.4	-	2.4	-	V
		I _O = -24 mA; V _{CCO} = 4.5 V		3.85	-	3.85	-	V
		I _O = -32 mA; V _{CCO} = 4.5 V		3.8	-	3.8	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IL}$	[2]					
		I _O = 100 μA; V _{CCO} = 1.2 V to 4.5 V		-	0.1	-	0.1	V
		I _O = 6 mA; V _{CCO} = 1.4 V		-	0.3	-	0.3	V
		I _O = 8 mA; V _{CCO} = 1.65 V		-	0.45	-	0.45	V
		I _O = 12 mA; V _{CCO} = 2.3 V		-	0.3	-	0.3	V
		I _O = 24 mA; V _{CCO} = 3.0 V		-	0.55	-	0.55	V
		I _O = 24 mA; V _{CCO} = 4.5 V		-	0.50	-	0.50	V
		I _O = 32 mA; V _{CCO} = 4.5 V		-	0.55	-	0.55	V
lı	input leakage current	V _I = 0 V to 5.5 V; V _{CCI} = 1.2 V to 5.5 V		-	±2	-	±10	μA
I _{OZ}	OFF-state output current	$V_{O} = 0 V \text{ or } V_{CCO};$ $V_{CCO} = 1.2 V \text{ to } 5.5 V$	[2]	-	±2	-	±10	μA
		suspend mode; $V_O = 0 V \text{ or } V_{CCO}$; $V_{CC(A)} = 5.5 V$; $V_{CC(B)} = 0 V$	[2]	-	±2	-	±10	μA
		suspend mode; $V_O = 0 V \text{ or } V_{CCO}$; $V_{CC(A)} = 0 V$; $V_{CC(B)} = 5.5 V$	[2]	-	±2	-	±10	μA
I _{OFF}	power-off leakage	A port; V ₁ or V _O = 0 V to 5.5 V; V _{CC(A)} = 0 V; V _{CC(B)} = 1.2 V to 5.5 V		-	±2	-	±10	μA
	current			-	±2	-	±10	μA

4-bit dual supply buffer/line driver; 3-state

Symbol	Parameter	Conditions	-40 °C t	o +85 °C	-40 °C to	o +125 °C	Unit
			Min	Max	Min	Max	
I _{CC}	supply current	A port; $V_1 = 0$ V or V_{CCI} ; $I_0 = 0$ A [1]					
		$V_{CC(A)}$, $V_{CC(B)}$ = 1.2 V to 5.5 V	-	15	-	20	μA
		V _{CC(A)} = 5.5 V; V _{CC(B)} = 0 V	-	15	-	20	μA
		V _{CC(A)} = 0 V; V _{CC(B)} = 5.5 V	-2	-	-4	-	μA
		B port; $V_I = 0$ V or V_{CCI} ; $I_O = 0$ A					
		$V_{CC(A)}$, $V_{CC(B)}$ = 1.2 V to 5.5 V	-	15	-	20	μA
		V _{CC(B)} = 0 V; V _{CC(A)} = 5.5 V	-2	-	-4	-	μA
		V _{CC(B)} = 5.5 V; V _{CC(A)} = 0 V	-	15	-	20	μA
		A plus B port ($I_{CC(A)} + I_{CC(B)}$); $I_O = 0$ A; $V_I = 0$ V or V_{CCI}					
		$V_{CC(A)}$, $V_{CC(B)}$ = 1.2 V to 5.5 V	-	25	-	30	μA
ΔI _{CC}	additional supply current	per input; V _{CC(A)} , V _{CC(B)} = 3.0 V to 5.5 V					
		$\begin{tabular}{lllllllllllllllllllllllllllllllllll$	-	50	-	75	μA
		A port; A port at V _{CC(A)} - 0.6 V; B port = open	-	50	-	75	μA
		B port; B port at V _{CC(B)} - 0.6 V; A port = open	-	50	-	75	μA

V_{CCI} is the supply voltage associated with the input port.
 V_{CCO} is the supply voltage associated with the output port.

10. Dynamic characteristics

Table 8. Typical dynamic characteristics at $V_{CC(A)}$ = 1.2 V and T_{amb} = 25 °C [1]

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 4; for waveforms see Fig. 2 and Fig. 3.

Symbol	Parameter	Conditions	V _{CC(B)}						Unit
			1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	5.0 V	
t _{pd}	propagation delay	An to YBn	15.6	11.6	9.8	7.8	6.9	6.3	ns
		B4 to YA4	15.6	14.5	14.0	13.5	13.3	13.8	ns
t _{dis}	disable time	OE to YA4	8.7	8.7	8.7	8.7	8.7	8.7	ns
		OE to YBn	11.9	9.2	8.7	7.4	7.7	6.8	ns
t _{en}	enable time	OE to YA4	17.5	17.5	17.5	17.5	17.5	17.5	ns
		OE to YBn	18.3	13.6	11.5	9.5	8.8	8.5	ns

[1] t_{pd} is the same as t_{PLL} and t_{PHL}; t_{dis} is the same as t_{PLZ} and t_{PHZ}; t_{en} is the same as t_{PZL} and t_{PZL}.

Table 9. Typical dynamic characteristics at $V_{CC(B)}$ = 1.2 V and T_{amb} = 25 °C [1]

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 4; for waveforms see Fig. 2 and Fig. 3.

Symbol	Parameter	Conditions	V _{CC(A)}						Unit
			1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	5.0 V	
t _{pd}	propagation delay	An to YBn	15.6	14.5	14.0	13.5	13.3	13.1	ns
		B4 to YA4	15.6	11.6	9.8	7.8	6.9	6.3	ns
t _{dis}	disable time	OE to YA4	8.7	6.1	5.5	3.9	4.1	2.9	ns
		OE to YBn	11.9	10.5	9.9	9.2	8.9	8.4	ns
t _{en}	enable time	OE to YA4	17.5	11.6	9.0	5.7	4.6	3.8	ns
		OE to YBn	18.3	17.0	16.4	15.8	15.6	15.4	ns

[1] t_{pd} is the same as t_{PLH} and t_{PHL} ; t_{dis} is the same as t_{PLZ} and t_{PHZ} ; t_{en} is the same as t_{PZL} and t_{PZH} .

Table 10. Typical power dissipation capacitance at $V_{CC(A)} = V_{CC(B)}$ and $T_{amb} = 25 \text{ °C } [1] [2]$ Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	$V_{CC(A)}$ and $V_{CC(B)}$						
			1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	5.0 V	
C _{PD}		inputs An, B4	0.5	0.5	0.5	0.7	0.9	1.3	pF
	capacitance	outputs YBn, YA4	12	12	12	12	12	12	pF

[1] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \Sigma (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where:}$

f_i = input frequency in MHz;

 f_o = output frequency in MHz;

C_L = load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

[2] $f_i = 10 \text{ MHz}$; $V_I = \text{GND}$ to V_{CC} ; $t_r = t_f = 1 \text{ ns}$; $C_L = 0 \text{ pF}$; $R_L = \infty \Omega$.

Table 11. Dynamic characteristics for temperature range -40 °C to +85 °C [1]

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 4; for waveforms see Fig. 2 and Fig. 3.

Symbol	Parameter	Conditions	V _{CC(B)}									Unit	
			1.5 V±0.1 V		1.8 V ±	0.15 V	2.5 V	± 0.2 V	3.3 V ± 0.3 V		5.0 V ± 0.5 V		
			Min	Max	Min	Мах	Min	Max	Min	Max	Min	Мах	
V _{CC(A)} =	1.5 V ± 0.1 V												
t _{pd}	propagation	An to YBn	1.7	20.7	1.6	17.1	1.3	12.9	1.1	11.1	1.0	9.5	ns
	delay	B4 to YA4	1.7	20.7	1.6	19.8	1.6	19.0	1.5	18.5	1.5	18.3	ns
t _{dis}	disable time	OE to YA4	1.3	11.6	1.3	11.6	1.3	11.6	1.3	11.6	1.3	11.6	ns
		OE to YBn	1.5	14.4	1.6	13.2	1.3	10.4	1.5	10.7	1.2	9.4	ns
t _{en}	enable time	OE to YA4	2.1	21.8	2.1	21.8	2.1	21.8	2.1	21.8	2.1	21.8	ns
		OE to YBn	2.1	22.2	1.8	18.4	1.5	14.2	1.3	12.5	1.2	11.4	ns
V _{CC(A)} =	1.8 V ± 0.15 V												
t _{pd}	propagation	An to YBn	1.6	19.8	1.4	16.2	1.2	11.9	1.0	10.2	0.9	8.5	ns
	delay	B4 to YA4	1.6	17.1	1.4	16.2	1.3	15.3	1.2	14.9	1.2	14.5	ns
t _{dis}	disable time	OE to YA4	1.4	10.1	1.4	10.1	1.4	10.1	1.4	10.1	1.4	10.1	ns
		OE to YBn	1.4	13.7	1.5	12.3	1.2	9.5	1.4	9.7	1.1	8.2	ns
t _{en}	enable time	OE to YA4	1.8	17.2	1.8	17.2	1.8	17.2	1.8	17.2	1.8	17.2	ns
		OE to YBn	2.0	21.4	1.7	17.4	1.4	12.9	1.2	11.1	1.1	9.8	ns
$V_{CC(A)} =$	2.5 V ± 0.2 V				·								
	propagation	An to YBn	1.6	19.0	1.3	15.3	1.0	11.0	0.9	9.1	0.7	7.2	ns
	delay	B4 to YA4	1.3	12.9	1.2	11.9	1.0	11.0	0.9	10.6	0.9	10.2	ns
t _{dis}	disable time	OE to YA4	0.9	7.2	0.9	7.2	0.9	7.2	0.9	7.2	0.9	7.2	ns
		OE to YBn	1.3	12.8	1.4	11.3	1.1	8.4	1.3	8.5	1.0	6.9	ns
t _{en}	enable time	OE to YA4	1.4	11.7	1.4	11.7	1.4	11.7	1.4	11.7	1.4	11.7	ns
		OE to YBn	2.0	20.8	1.6	16.6	1.3	11.9	1.2	9.9	1.0	8.2	ns
$V_{CC(A)} =$	3.3 V ± 0.3 V				·								
t _{pd}	propagation	An to YBn	1.5	18.5	1.2	14.9	0.9	10.6	0.8	8.5	0.7	6.6	ns
	delay	B4 to YA4	1.1	11.1	1.0	10.2	0.9	9.1	0.8	8.5	0.7	8.1	ns
t _{dis}	disable time	OE to YA4	1.1	7.2	1.1	7.2	1.1	7.2	1.1	7.2	1.1	7.2	ns
		OE to YBn	1.2	12.3	1.3	10.9	1.0	8.0	1.2	8.0	0.9	6.3	ns
t _{en}	enable time	OE to YA4	1.2	9.3	1.2	9.3	1.2	9.3	1.2	9.3	1.2	9.3	ns
		OE to YBn	2.0	20.4	1.7	16.5	1.4	11.5	1.2	9.4	1.0	7.5	ns
V _{CC(A)} =	5.0 V ± 0.5 V												
t _{pd}	propagation	An to YBn	1.5	18.3	1.2	14.5	0.9	10.2	0.7	8.1	0.6	6.3	ns
	delay	B4 to YA4	1.0	9.5	0.9	8.5	0.7	7.2	0.7	6.6	0.6	6.3	ns
t _{dis}	disable time	OE to YA4	0.7	5.3	0.7	5.3	0.7	5.3	0.7	5.3	0.7	5.3	ns
		OE to YBn	1.2	12.0	1.3	10.5	0.9	7.6	1.2	7.6	0.8	5.8	ns
t _{en}	enable time	OE to YA4	1.1	7.0	1.1	7.0	1.1	7.0	1.1	7.0	1.1	7.0	ns
		OE to YBn	2.0	20.5	1.7	16.4	1.4	11.4	1.2	9.2	1.0	7.2	ns

 $[1] \quad t_{pd} \text{ is the same as } t_{PLH} \text{ and } t_{PHL}; \ t_{dis} \text{ is the same as } t_{PLZ} \text{ and } t_{PHZ}; \ t_{en} \text{ is the same as } t_{PZL} \text{ and } t_{PZH}.$

Table 12. Dynamic characteristics for temperature range -40 °C to +125 °C [1]

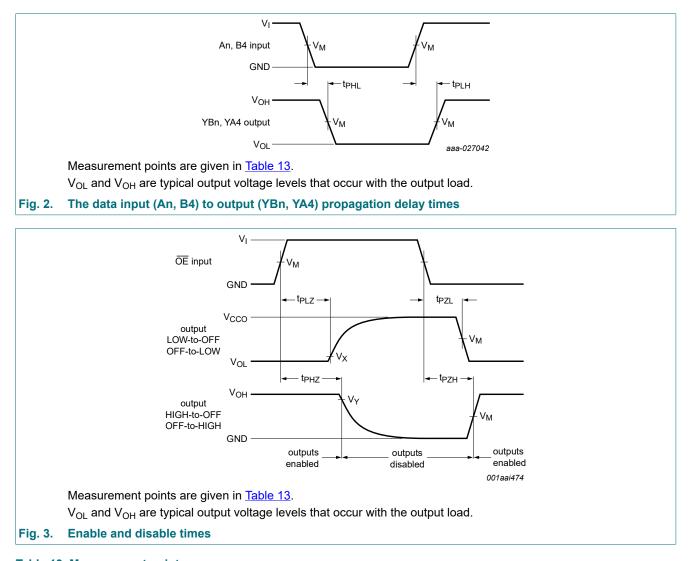
Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 4; for waveforms see Fig. 2 and Fig. 3.

Symbol	Parameter	Conditions	V _{CC(B)}									Unit	
			1.5 V±0.1 V		1.8 V ±	:0.15 V	2.5 V :	± 0.2 V	3.3 V	±0.3 V	5.0 V	±0.5 V	
			Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
V _{CC(A)} =	1.5 V ± 0.1 V												
t _{pd}	propagation	An to YBn	1.7	22.0	1.6	18.3	1.3	14.0	1.1	12.2	1.0	10.5	ns
	delay	B4 to YA4	1.7	22.0	1.6	21.0	1.6	20.1	1.5	19.5	1.5	19.4	ns
t _{dis}	disable time	OE to YA4	1.3	12.8	1.3	12.8	1.3	12.8	1.3	12.8	1.3	12.8	ns
		OE to YBn	1.5	15.8	1.6	14.5	1.3	11.5	1.5	11.1	1.2	9.7	ns
t _{en}	enable time	OE to YA4	2.1	23.2	2.1	23.2	2.1	23.2	2.1	23.2	2.1	23.2	ns
		OE to YBn	2.1	23.6	1.8	19.6	1.5	15.4	1.3	13.7	1.2	12.6	ns
V _{CC(A)} =	1.8 V ± 0.15 V												
t _{pd}	propagation	An to YBn	1.6	21.0	1.4	17.4	1.2	13.0	1.0	11.2	0.9	9.3	ns
	delay	B4 to YA4	1.6	18.3	1.4	17.4	1.3	16.4	1.2	16.0	1.2	15.6	ns
t _{dis}	disable time	OE to YA4	1.4	11.2	1.4	11.2	1.4	11.2	1.4	11.2	1.4	11.2	ns
		OE to YBn	1.4	15.2	1.5	13.5	1.2	10.5	1.4	10.0	1.1	8.5	ns
t _{en}	t _{en} enable time	OE to YA4	1.8	18.4	1.8	18.4	1.8	18.4	1.8	18.4	1.8	18.4	ns
		OE to YBn	2.0	22.7	1.7	18.7	1.4	14.1	1.2	12.2	1.1	10.8	ns
$V_{CC(A)} =$	2.5 V ± 0.2 V	1		1	I	1	1	1	1	1	1	1	.1
	propagation	An to YBn	1.6	20.1	1.3	16.4	1.0	11.9	0.9	9.9	0.7	7.9	ns
	delay	B4 to YA4	1.3	14.0	1.2	13.0	1.0	11.9	0.9	11.5	0.9	11.1	ns
t _{dis}	disable time	OE to YA4	0.9	8.0	0.9	8.0	0.9	8.0	0.9	8.0	0.9	8.0	ns
		OE to YBn	1.3	14.0	1.4	12.5	1.1	9.3	1.3	9.3	1.0	7.5	ns
t _{en}	enable time	OE to YA4	1.4	12.7	1.4	12.7	1.4	12.7	1.4	12.7	1.4	12.7	ns
		OE to YBn	2.0	22.0	1.6	17.9	1.3	13.0	1.2	10.8	1.0	9.0	ns
$V_{CC(A)} =$	3.3 V ± 0.3 V			1	I		1	1		1		1	
t _{pd}	propagation	An to YBn	1.5	19.5	1.2	16.0	0.9	11.5	0.8	9.3	0.7	7.3	ns
	delay	B4 to YA4	1.1	12.2	1.0	11.2	0.9	9.9	0.8	9.3	0.7	8.8	ns
t _{dis}	disable time	OE to YA4	1.1	7.8	1.1	7.8	1.1	7.8	1.1	7.8	1.1	7.8	ns
		OE to YBn	1.2	13.6	1.3	12.1	1.0	8.8	1.2	8.3	0.9	6.5	ns
t _{en}	enable time	OE to YA4	1.2	10.1	1.2	10.1	1.2	10.1	1.2	10.1	1.2	10.1	ns
		OE to YBn	2.0	21.6	1.7	17.5	1.4	12.6	1.2	10.3	1.0	8.3	ns
$V_{CC(A)} =$	5.0 V ± 0.5 V			1				1		1		1	-
t _{pd}	propagation	An to YBn	1.5	19.4	1.2	15.6	0.9	11.1	0.7	8.8	0.6	6.8	ns
	delay	B4 to YA4	1.0	10.5	0.9	9.3	0.7	7.9	0.7	7.3	0.6	6.8	ns
t _{dis}	disable time	OE to YA4	0.7	5.7	0.7	5.7	0.7	5.7	0.7	5.7	0.7	5.7	ns
		OE to YBn	1.2	13.3	1.3	11.7	0.9	8.4	1.2	7.9	0.8	6.0	ns
t _{en}	enable time	OE to YA4	1.1	7.7	1.1	7.7	1.1	7.7	1.1	7.7	1.1	7.7	ns
		OE to YBn	2.0	21.7	1.7	17.4	1.4	12.5	1.2	10.1	1.0	7.9	ns

 $[1] \quad t_{pd} \text{ is the same as } t_{PLH} \text{ and } t_{PHL}; \ t_{dis} \text{ is the same as } t_{PLZ} \text{ and } t_{PHZ}; \ t_{en} \text{ is the same as } t_{PZL} \text{ and } t_{PZH}.$

4-bit dual supply buffer/line driver; 3-state

10.1. Waveforms and test circuit



Supply voltage	Input [1]	Output [2]	Output [2]				
V _{CC(A)} , V _{CC(B)}	V _M	V _M	V _X	V _Y			
1.2 V to 1.6 V	0.5 × V _{CCI}	$0.5 \times V_{CCO}$	V _{OL} + 0.1 V	V _{OH} - 0.1 V			
1.65 V to 2.7 V	0.5 × V _{CCI}	0.5 × V _{CCO}	V _{OL} + 0.15 V	V _{OH} - 0.15 V			
3.0 V to 5.5 V	0.5 × V _{CCI}	$0.5 \times V_{CCO}$	V _{OL} + 0.3 V	V _{OH} - 0.3 V			

[1] V_{CCI} is the supply voltage associated with the input port.

[2] V_{CCO} is the supply voltage associated with the output port.

4-bit dual supply buffer/line driver; 3-state

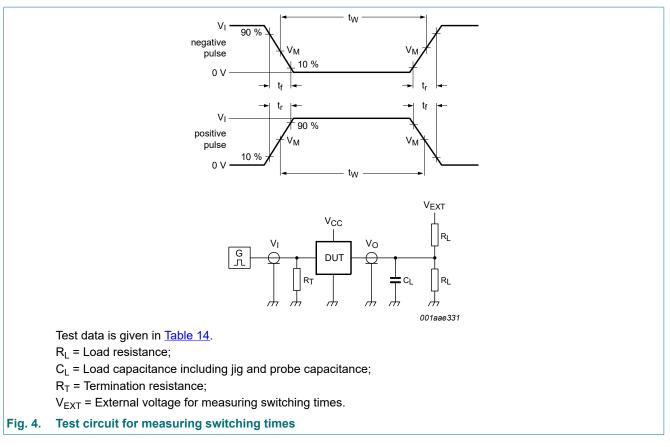


Table 14. Test data

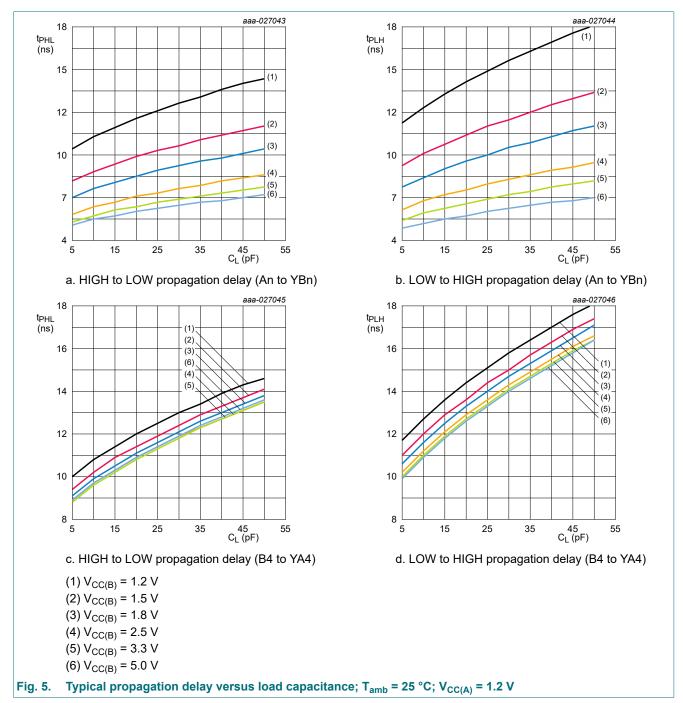
Supply voltage Input		Load		V _{EXT}			
$V_{CC(A)}, V_{CC(B)}$	V _I [1]	Δt/ΔV [2]	CL	R _L	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ} [3]
1.2 V to 5.5 V	V _{CCI}	≤ 1.0 ns/V	15 pF	2 kΩ	open	GND	2 × V _{CCO}

[1] V_{CCI} is the supply voltage associated with the input port.

[2] dV/dt ≥ 1.0 V/ns.

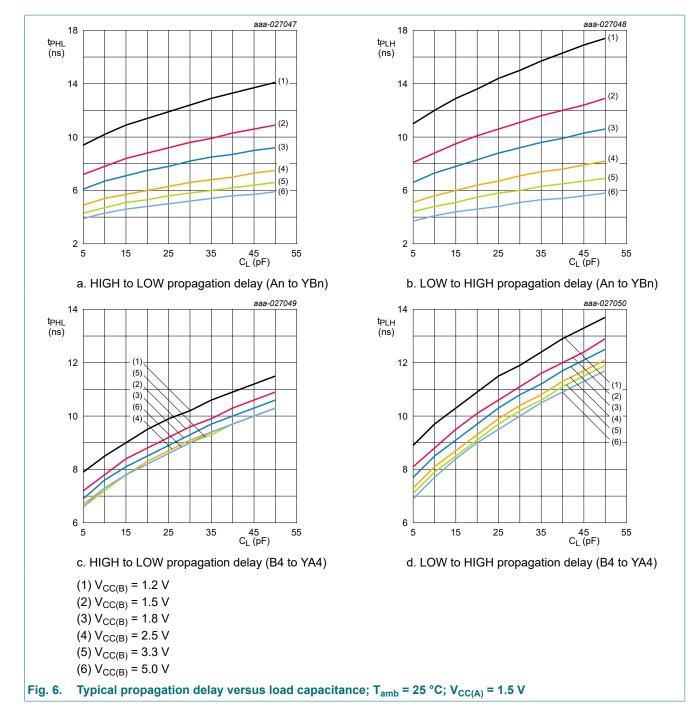
[3] V_{CCO} is the supply voltage associated with the output port.

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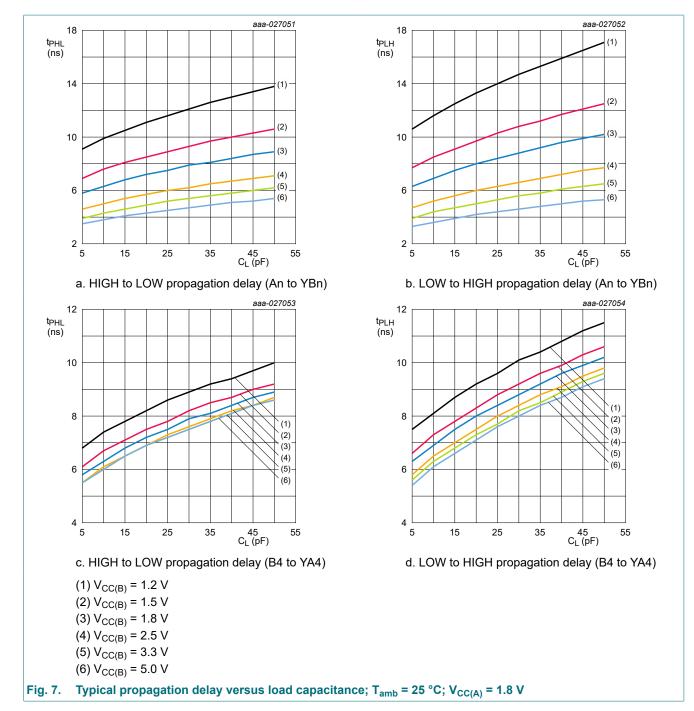
10.2. Typical propagation delay characteristics

4-bit dual supply buffer/line driver; 3-state

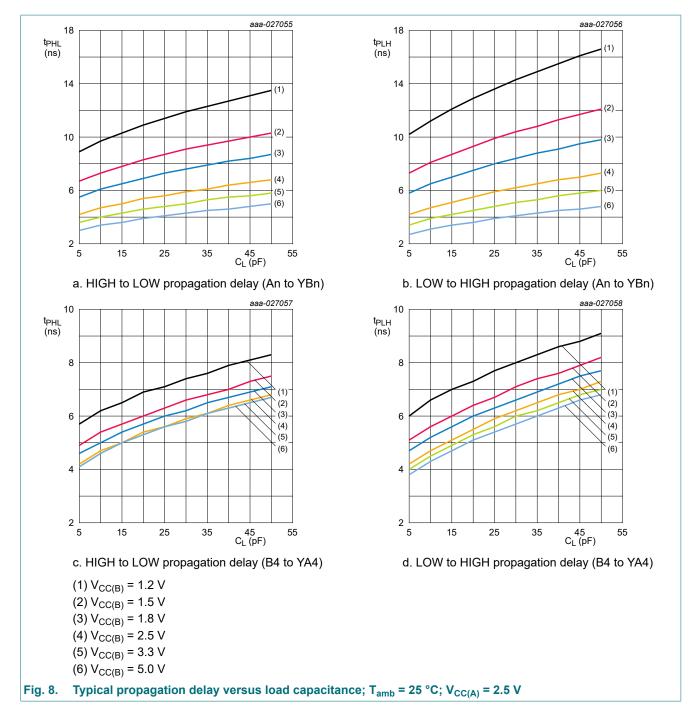


Product data sheet

4-bit dual supply buffer/line driver; 3-state

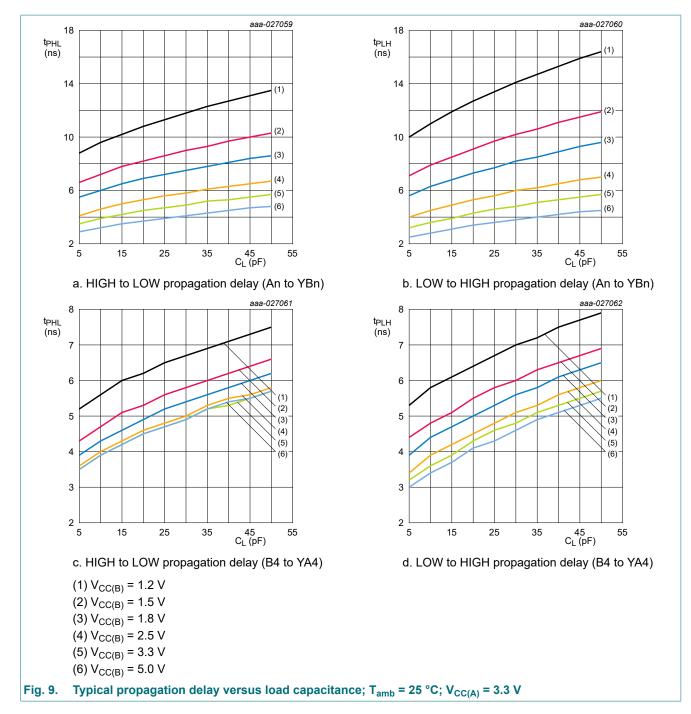


4-bit dual supply buffer/line driver; 3-state

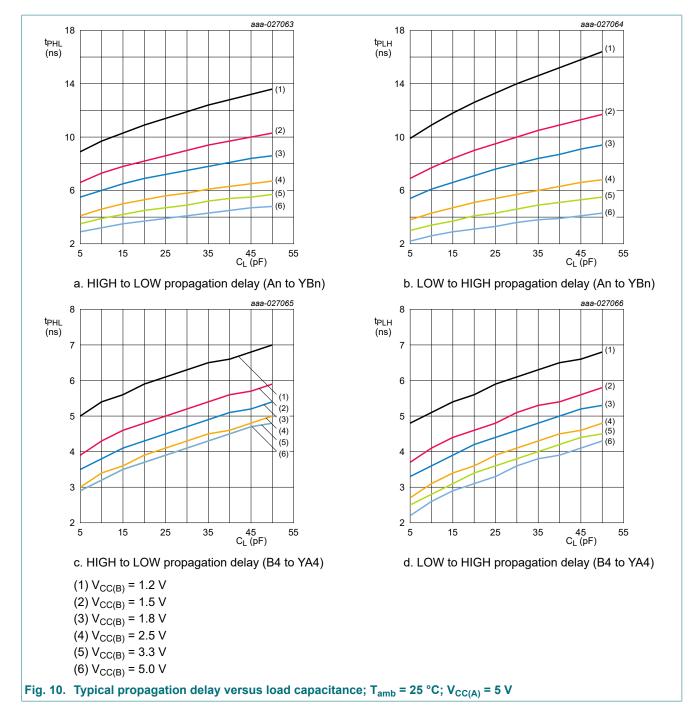


Product data sheet

4-bit dual supply buffer/line driver; 3-state



4-bit dual supply buffer/line driver; 3-state



Product data sheet

11. Application information

11.1. Unidirectional logic level-shifting application

The circuit given in Fig. 11 is an example of the 74LVC4T3144 being used in an unidirectional logic level-shifting application.

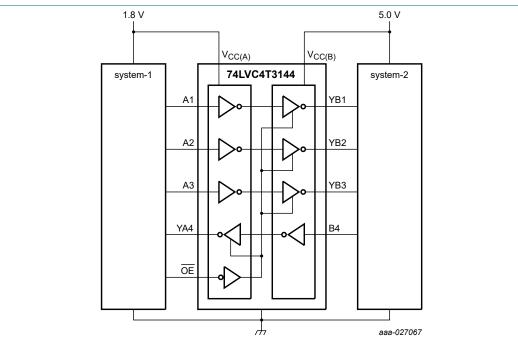


Fig. 11. Unidirectional logic level-shifting application

Table 15. Description unidirectional logic level-shifting application

Name	Description
V _{CC(A)}	supply voltage of system-1 (1.2 V to 5.5 V)
V _{CC(B)}	supply voltage of system-2 (1.2 V to 5.5 V)
A1, A2, A3	input level depends on $V_{CC(A)}$ voltage
YA4	output level depends on V _{CC(A)} voltage
YB1, YB2, YB3	output level depends on $V_{CC(B)}$ voltage
B4	input level depends on $V_{CC(B)}$ voltage
OE	input level depends on V _{CC(A)} voltage
GND	device GND

11.2. Power-up considerations

The device is designed such that no special power-up sequence is required other than GND being applied first.

Table 16. Typical total supply current (I_{CC(A)} + I_{CC(B)})

V _{CC(A)}	V _{CC(B)}									
	0 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	5.0 V			
0 V	0	< 1	< 1	< 1	< 1	< 1	< 1	μA		
1.2 V	< 1	< 1	< 1	< 1	< 1	< 1	1	μA		
1.5 V	< 1	< 1	< 1	< 1	< 1	< 1	< 1	μA		
1.8 V	< 1	< 1	< 1	< 1	< 1	< 1	< 1	μA		
2.5 V	< 1	< 1	< 1	< 1	< 1	< 1	< 1	μA		
3.3 V	< 1	< 1	< 1	< 1	< 1	< 1	< 1	μA		
5.0 V	< 1	1	< 1	< 1	< 1	< 1	< 1	μA		

4-bit dual supply buffer/line driver; 3-state

12. Package outline

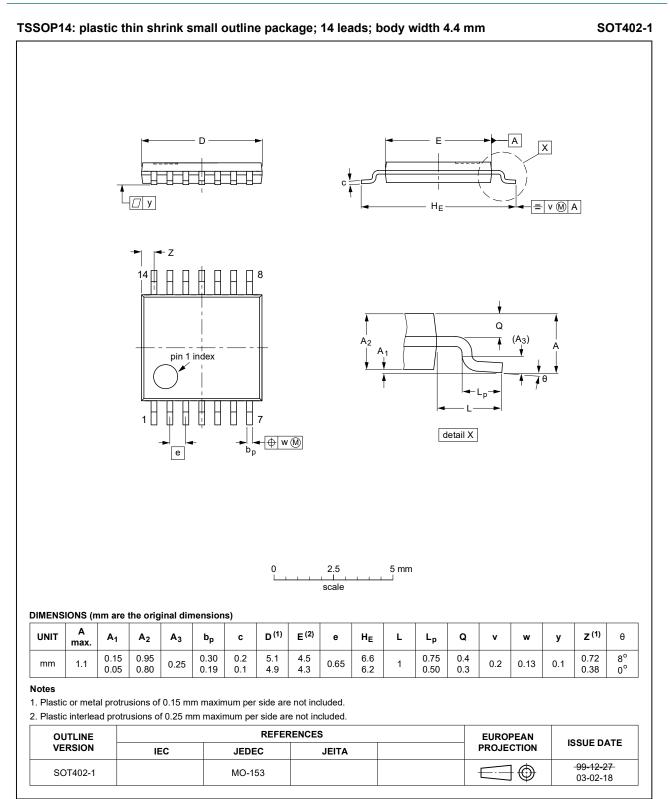


Fig. 12. Package outline SOT402-1 (TSSOP14)

74LVC4T3144_Q100

13. Abbreviations

Table 17. Abbreviations					
Acronym	Description				
CDM	Charged Device Model				
DUT	Device Under Test				
ESD	ElectroStatic Discharge				
HBM	Human Body Model				

14. Revision history

Table 18. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes				
74LVC4T3144_Q100 v.2	20230803	Product data sheet	-	74LVC4T3144_Q100 v.1				
Modifications:		 <u>Section 2</u>: ESD specification updated according to the latest JEDEC standard. <u>Section 7</u>: Derating values for P_{tot} total power dissipation updated. 						
74LVC4T3144_Q100 v.1	20170814	Product data sheet	-	-				

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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Product data sheet

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